2SA1693

**Preliminary** 

PNP EPITAXIAL SILICON TRANSISTOR

# SILICON PNP EPITAXIAL PLANAR TRANSISTOR

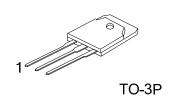
#### **■** DESCRIPTION

The UTC **2SA1693** is a silicon PNP epitaxial planar transistor, it uses UTC's advanced technology to provide the customers with high DC current gain and high collector-base breakdown voltage, etc.

The UTC **2SA1693** is suitable for audio and general purpose, etc.

## **■ FEATURES**

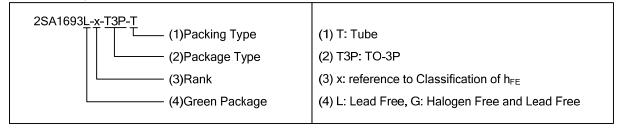
- \* High DC current gain
- \* High collector-base breakdown voltage



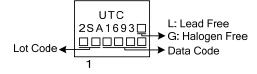
## **■ ORDERING INFORMATION**

Ordering	Number	Deelsene	Pin Assignment		Pin Assignment		Dealing
Lead Free	Halogen Free	Package		2	3	Packing	
2SA1693L-x-T3P-T	2SA1693G-x-T3P-T	TO-3P	В	С	Е	Tube	

Note: Pin Assignment: B: Base C: Collector E: Emitter



#### ■ MARKING



<u>www.unisonic.com.tw</u> 1 of 3

# ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	$V_{CBO}$	-80	V
Collector-Emitter Voltage	$V_{CEO}$	-80	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Collector Current	Ic	-6	Α
Base Current	I <sub>B</sub>	-3	Α
Collector Power Dissipation (T <sub>C</sub> =25°C)	Pc	60	W
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

# ■ **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
PARAIVIETER		STWBOL	TEST CONDITIONS	IVIIIN	III	IVIAA	OIVII
Collector Cut-Off Current		I <sub>CBO</sub>	V <sub>CB</sub> =-80V			-10	μΑ
Emitter Cut-Off Current		I <sub>EBO</sub>	V <sub>EB</sub> =-6V			-10	μΑ
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	I <sub>C</sub> =-50mA				V
DC Current Gain		h <sub>FE</sub>	V <sub>CE</sub> =-4V, I <sub>C</sub> =-2A	50		180	
Collector-Emitter Saturation Voltage		V <sub>CE(SAT)</sub>	I <sub>C</sub> =-2A, I <sub>B</sub> =-0.2A			-1.5	V
Current Gain Bandwidth Product		f⊤	V <sub>CE</sub> =-12V, I <sub>E</sub> =0.5A		20		MHz
Output Capacitance		Cob	V <sub>CB</sub> =-10V, f=1MHz		150		pF
Switching time	Turn-on time	ton	V <sub>CC</sub> =-30V, R <sub>L</sub> =10Ω, I <sub>C</sub> =-3A, I <sub>B1</sub> =0.3A I <sub>B2</sub> =0.3A		0.18		μS
	Storage time	ts			1.10		μS
	Fall time	$t_{F}$			0.21		μS

# ■ CLASSIFICATION OF h<sub>FE</sub>

RANK	0	Р	Y
RANGE	50~100	70~140	90~180

## **■ TEST CIRCUIT**

INPUT 
$$I_{B2}$$
 OUTPUT  $I_{B1}$   $I_{B2}$  OUTPUT  $I_{B1}$   $I_{B2}$   $I_{B2}$   $I_{B1}$   $I_{B2}$   $I_{B2}$ 

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